

PCS/CELLULAR TDMA/CDMA/W-CDMA LINEAR VARIABLE GAIN AMPLIFIER

RF2381

Typical Applications

- CDMA PCS/Cellular Handsets
- TDMA PCS/Cellular Handsets

Product Description

The RF2381 is a linear variable gain amplifier suitable for use in TDMA and CDMA systems in the cellular or PCS band and for W-CDMA systems. The features of this device include linear gain control, high gain, and high linearity. The IC is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (GaAs HBT) process and is featured in an industry-standard miniature 6-lead plastic SOT package.







Functional Block Diagram

Package Style: SOT23-6

Features

W-CDMA Handsets

- 50dB Linear Gain Control Range
- 22dB Maximum Gain
- Single 2.7V to 3.3V Supply
- 35mA Supply Current
- High Linearity

Ordering In	Ordering Information			
RF2381	2381 PCS/Cellular TDMA/CDMA/W-CDMA Linear Vari- able Gain Amplifier			
RF2381 PCBA	Fully Assembled Evaluation	on Board		
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Greensboro, NC 27409, USA http://www.rfmd.com				

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	0 to +5.0	V _{DC}
DC Current	100	mA
Operating Ambient Temperature	-30 to +85	°C
Storage Temperature	-40 to +150	°C



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Deremeter	Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition
Overall					V _{CC} =2.8V, V _{GC} =2.0V, T=25°C
Usable Frequency Range		800 to 2100		MHz	
Linear Gain Control Range	50			dB	
Gain Control Slope		70		dB/V	
Input VSWR		1.5:1	2.5:1		Over entire gain control range
Output VSWR		1.5:1	2.5:1		Over entire gain control range
Output IP3	+23	+26		dBm	
Noise Figure		9		dB	Maximum gain
TDMA					V _{CC} =2.8V, V _{GC} =2.0V, T=25°C
Operating Frequency		1880		MHz	
Maximum Small Signal Gain	18	20	22	dB	
Maximum Average Output Power		+8		dBm	TDMA modulation; ACP≤-32dBc
Maximum Average Input Power		-9	-8	dBm	TDMA modulation; for any V _{GC} that gives
					P _{OUT} ≤+8dBm, ACP≤-32dBc, ALT≤-52dBc
Adjacent Channel Power		-33	-32	dBc	TDMA modulation; P _{OUT} ≤+8dBm and
					P _{IN} ≤-11 dBm, at all V _{GC} .
		-61	-52	dBc	TDMA modulation; P _{OUT} ≤+8dBm and
		0.		420	$P_{IN} \leq -11 dBm$, at all V_{GC} .
CDMA					$V_{CC} = 2.8 V, V_{GC} = 2.0 V, T = 25 ^{\circ}C$
Operating Frequency		1880		MHz	
Maximum Small Signal Gain	18	20	22	dB	
Maximum Average Output Power	10	+6	~~~	dBm	CDMA modulation; V _{CC} =3.0V, maximum
Maximum / Welage Output / Owel		10		dBiii	gain setting, $ACP \le -52 dBc$.
Maximum Average Input Power		-13		dBm	CDMA modulation; for any V_{GC} that gives
				02	$P_{OUT} \le +6$ dBm, ACP ≤ -52 dBc
Adjacent Channel Power		-53		dBc	CDMA modulation; $V_{CC}=3.0V$.
Adjacent Channer i Ower		-55		ubc	$P_{OUT} \le +6$ dBm and $P_{IN} \le -13$ dBm, at all V_{GC} .
W-CDMA					$V_{CC}=2.8V, V_{GC}=2.0V, T=25^{\circ}C$
		1000 to 1000		N411-	V _{CC} -2.0V, V _{GC} -2.0V, 1-23 C
Operating Frequency	17.5	1920 to 1980 19.5	22	MHz dB	
Small Signal Gain Maximum Linear Output Power	C.11	19.5	22	dB dBm	W-CDMA ACP<-46dBc
Adjacent Channel Power		- 1	-46	dBm dBc	
Adjacent Channel Power			-40	UDC	W-CDMA modulation; P _{OUT} ≤+5dBm and P _{IN} <-12dBm
			-43	dBc	W-CDMA modulation; Over entire gain con- trol range, P _{IN} <-17dBm
			-43	dBc	W-CDMA modulation; V _{GC} =1.0V,
					P _{IN} <-14dBm

4

Deremeter		Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Power Supply					T=25°C	
Supply Voltage		2.8		V	Specifications	
		2.7 to 3.3		V	Operating range	
Gain Control Voltage (V _{GC})		0 to 2.2		V		
Supply Current		35		mA	V _{CC} =2.8V, V _{GC} =2.2V	
		50		mA	V _{CC} =2.8V, V _{GC} =2.2V V _{CC} =3.3V, V _{GC} =2.2V	
		21		mA	V _{CC} =2.8V, V _{GC} =0.4V	
V _{GC} Current	-2.0		+2.4	mA	V_{GC} =0.4V to 2.2V	

Pin	Function	Description	Interface Schematic
1	RF OUT	RF output pin. This pin is DC-coupled and requires V _{CC} through a bias inductor sized accordingly to provide a high pass transformation with a series capacitor.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
3	GC	Analog gain control pin. This pin controls the gain of the IC. Minimum gain occurs at V_{GC} <0.4V and maximum gain is achieved with V_{GC} =2.0V. 50dB of linear gain control with little variation of input P _{1dB} is available.	
4	RF IN	RF input pin. This pin is DC-coupled.	
5	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
6	VCC	Power supply. This pin should be connected to a regulated supply and requires a series inductor and bypass capacitor. Voltage is supplied through this pin to the first stage collector; this voltage also controls the bias. Gain may be tuned by adjusting the value of the feed inductor.	

Application Schematic 1850MHz to 1910MHz



*For W-CDMA, use 2.2 nH

4

Evaluation Board Schematic



Evaluation Board Layout Board Size 2.0" x 2.0" Board Thickness 0.028", Board Material FR-4, Multi-Layer











Gain versus Gain-Control Voltage over Temperature, P_{IN}=-9 dBm, F-1880 MHz, V_{CC}=2.8 V







4